

PC716V

High Sensitivity, High Output Type Photocoupler

- * Lead forming type (I type) and taping reel type (P type) are also available. (PC716VI/PC716VP)
- *** TÜV (VDE0884) approved type is also available as an option.

■ Features

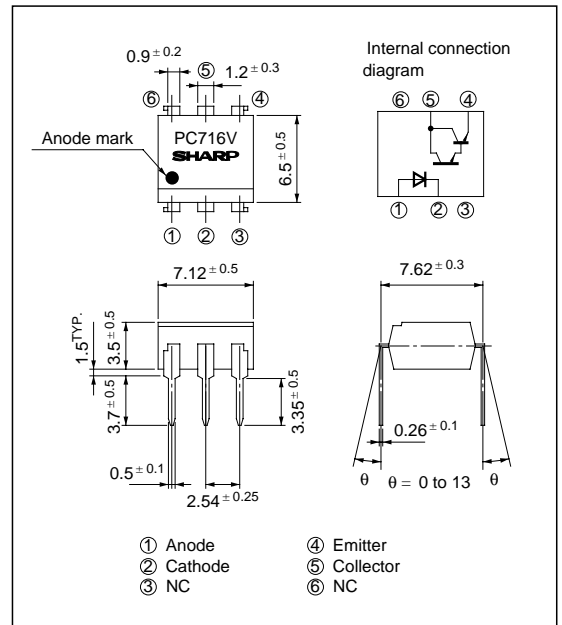
1. High current transfer ratio
(CTR : MIN. 1 000% at $I_F = 1\text{mA}$, $V_{CE} = 2\text{V}$)
2. High collector power dissipation
(P_c : 300mW)
3. High isolation voltage between input and output
(V_{iso} : 5 000V_{rms})
4. Recognized by UL, file No. E64380

■ Applications

1. DC-DC SSRs
2. Power monitors, welding machines
3. System appliances, measuring instruments
4. Signal transmission between circuits of different potentials and impedances

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	*1 Peak forward current	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V_{CEO}	35	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_C	200	mA
	Collector power dissipation	P_C	300	mW
Total power dissipation		P_{tot}	350	mW
*2 Isolation voltage		V_{iso}	5 000	V _{rms}
Operating temperature		T_{opr}	- 25 to + 100	$^\circ\text{C}$
Storage temperature		T_{stg}	- 40 to + 125	$^\circ\text{C}$
*3 Soldering temperature		T_{sol}	260	$^\circ\text{C}$

*1 Pulse width $\leq 100\ \mu\text{s}$, Duty ratio : 0.001

*2 40 to 60% RH, AC for 1 minute

*3 For 10 seconds

■ Electro-optical Characteristics

($T_a = 25^\circ\text{C}$)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage	V_F	$I_F = 10\text{mA}$	-	1.2	1.4	V	
	Peak forward voltage	V_{FM}	$I_{FM} = 0.5\text{A}$	-	-	3.0	V	
	Reverse current	I_R	$V_R = 4\text{V}$	-	-	10	μA	
	Terminal capacitance	C_t	$V = 0, f = 1\text{kHz}$	-	30	250	pF	
Output	Collector dark current	I_{CEO}	$V_{CE} = 10\text{V}, I_F = 0$	-	-	10^{-6}	A	
Transfer characteristics	Current transfer ratio	CTR	$I_F = 1\text{mA}, V_{CE} = 2\text{V}$	1 000	6 000	15 000	%	
	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_F = 20\text{mA}, I_C = 10\text{mA}$	-	-	1.2	V	
	Isolation resistance	R_{ISO}	DC500V, 40 to 60% RH	5×10^{10}	10^{11}	-	Ω	
	Floating capacitance	C_f	$V = 0, f = 1\text{MHz}$	-	0.6	1.0	pF	
	Response time	Cut-off frequency	f_c	$V_{CE} = 2\text{V}, I_C = 10\text{mA}, R_L = 100\Omega, -3\text{dB}$	-	3	-	kHz
		Rise time	t_r	$V_{CE} = 2\text{V}, I_C = 20\text{mA}, R_L = 100\Omega$	-	130	400	μs
Fall time	t_f	-	60		350	μs		

Fig. 1 Forward Current vs. Ambient Temperature

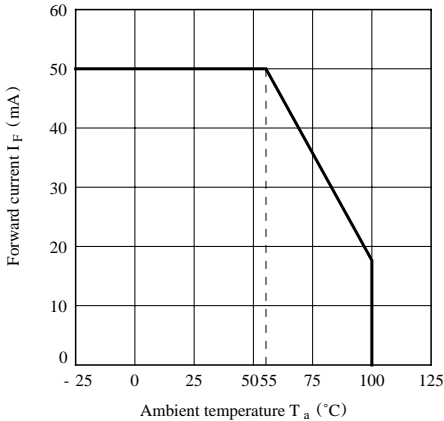


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

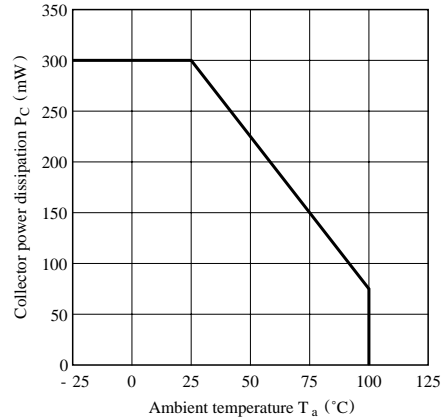


Fig. 3 Peak Forward Current vs. Duty Ratio

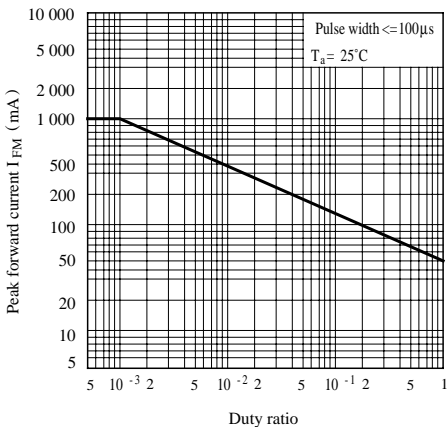


Fig. 4 Forward Current vs. Forward Voltage

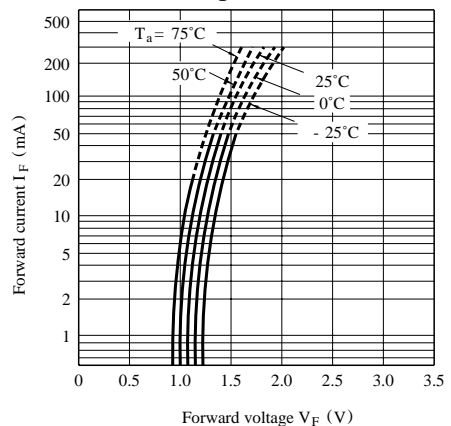


Fig. 5 Current Transfer Ratio vs. Forward Current

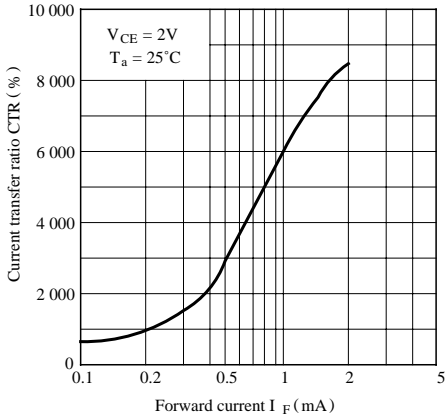


Fig. 6-a Collector Current vs. Collector-emitter Voltage

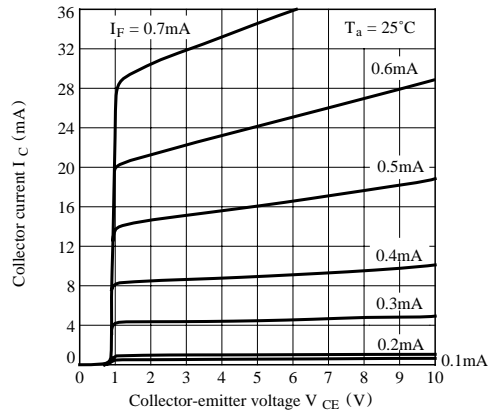


Fig. 6-b Collector Current vs. Collector-emitter Voltage

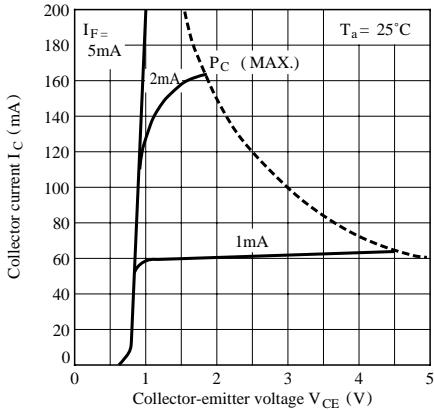


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

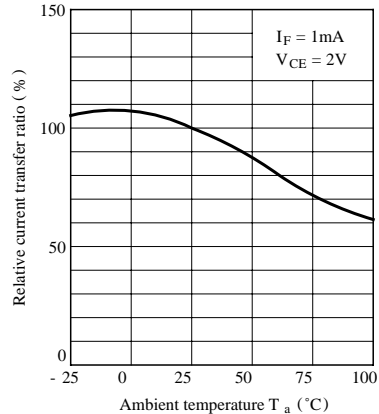


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

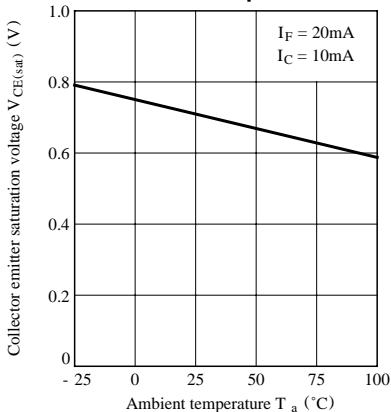


Fig. 9 Collector Dark Current vs. Ambient Temperature

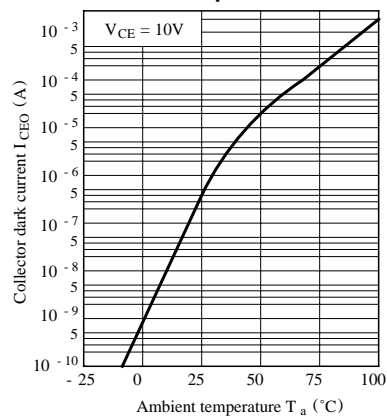
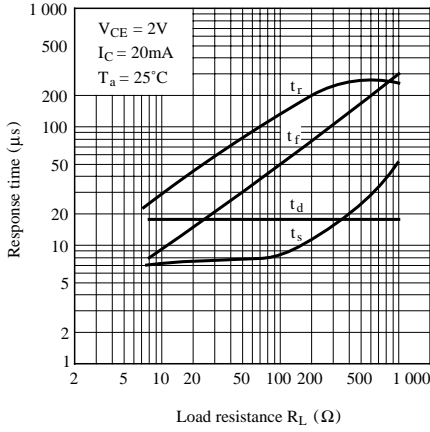


Fig.10 Response Time vs. Load Resistance



Test Circuit for Response Time

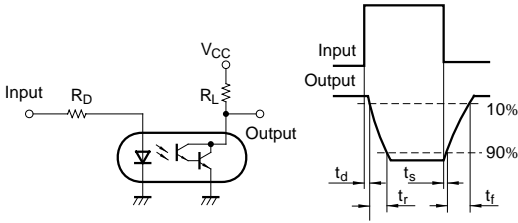
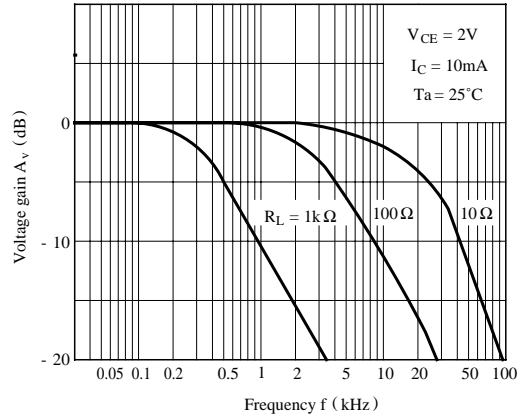
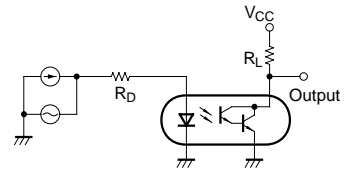


Fig.11 Frequency Response



Test Circuit for Frequency Response



● Please refer to the chapter “Precautions for Use”.